

## CDBD2SC21200-G

Reverse Voltage: 1200V

Forward Current: 2A

RoHS Device



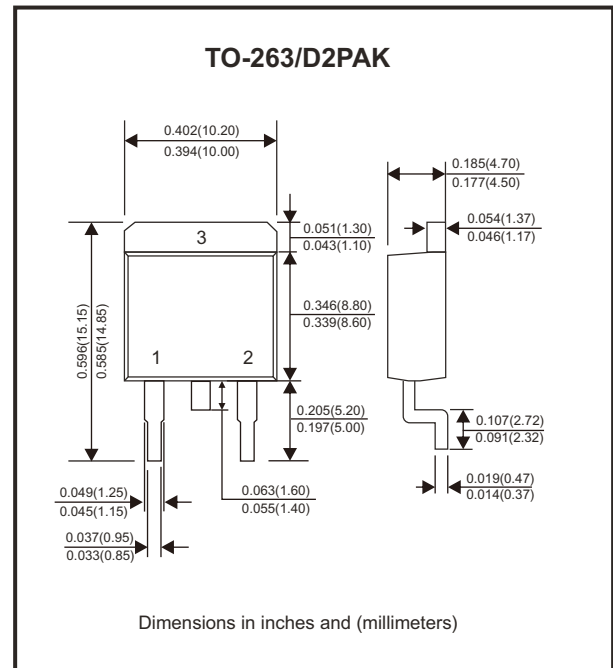
### Features

- Rated to 1200V at 2 Amps
- Short recovery time.
- High speed switching possible.
- High frequency operation.
- High temperature operation.
- Temperature independent switching behaviour.
- Positive temperature coefficient on  $V_F$ .

### Mechanical data

- Case: TO-263/D2PAK, molded plastic.
- Terminals: Solderable per MIL-STD-750, method 2026.

### Circuit Diagram



### Maximum Ratings (at $T_A=25^\circ\text{C}$ , unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Repetitive peak reverse voltage		$V_{RRM}$	1200	V
Surge peak reverse voltage		$V_{RSM}$	1200	V
DC blocking voltage		$V_{DC}$	1200	V
Continuous forward current	$T_C = 155^\circ\text{C}$	$I_F$	2	A
Repetitive peak forward surge current	$T_C = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ Half sine wave, $D = 0.3$	$I_{FRM}$	15	A
Non-repetitive peak forward surge current	$T_C = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ Half sine wave	$I_{FSM}$	35	A
Power dissipation	$T_C = 25^\circ\text{C}$	$P_{TOT}$	53.2	W
	$T_C = 110^\circ\text{C}$		23	
Typical thermal resistance	Junction to case	$R_{\theta JC}$	2.82	$^\circ\text{C/W}$
Operating junction temperature range		$T_J$	-55 ~ +175	$^\circ\text{C}$
Storage temperature range		$T_{STG}$	-55 ~ +175	$^\circ\text{C}$

## Electrical Characteristics (at $T_A=25^\circ\text{C}$ , unless otherwise noted)

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 2\text{A}, T_J = 25^\circ\text{C}$	$V_F$		1.62	1.7	V
	$I_F = 2\text{A}, T_J = 175^\circ\text{C}$			2.8	3	
Reverse current	$V_R = 1200\text{V}, T_J = 25^\circ\text{C}$	$I_R$		20	100	$\mu\text{A}$
	$V_R = 1200\text{V}, T_J = 175^\circ\text{C}$			30	200	
Total capacitive charge	$V_R = 800\text{V}, T_J = 150^\circ\text{C}$ $Q_C = \int_0^{V_R} C(V) dv$	$Q_C$		12		nC
Total capacitance	$V_R = 0\text{V}, T_J = 25^\circ\text{C}, f = 1\text{MHz}$	C		136	150	pF
	$V_R = 400\text{V}, T_J = 25^\circ\text{C}, f = 1\text{MHz}$			12	13	
	$V_R = 800\text{V}, T_J = 25^\circ\text{C}, f = 1\text{MHz}$			11	12	

## Rating and Characteristics Curves (CDBD2SC21200-G)

Fig.1 - Forward Characteristics

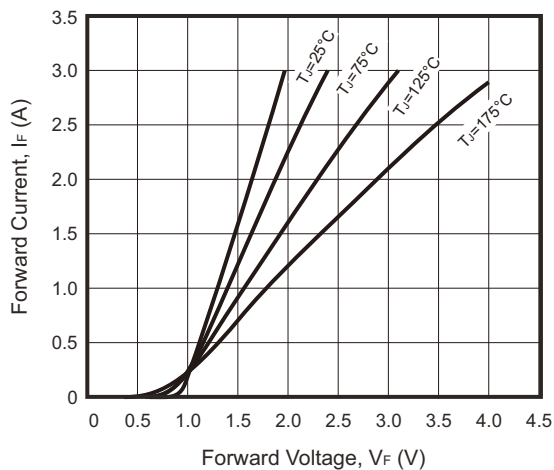


Fig.2 - Reverse Characteristics

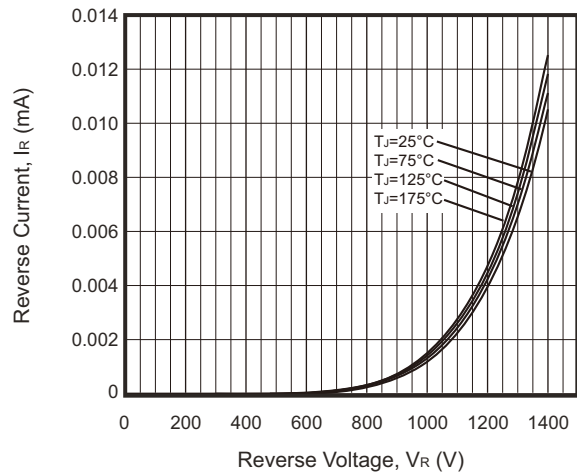


Fig.3 - Current Derating

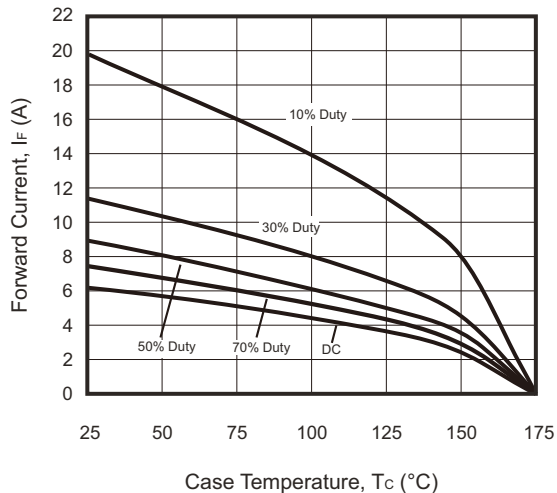
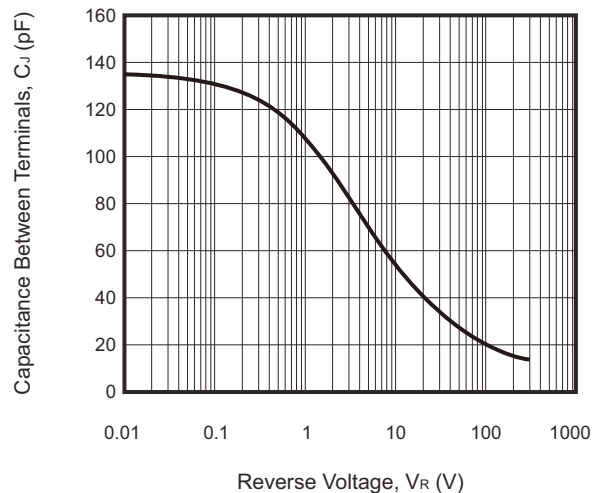
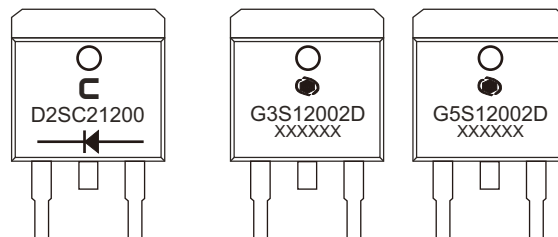


Fig.4 - Capacitance VS. Reverse Voltage



## Marking Code

Part Number	Marking Code
CDBD2SC21200-G	D2SC21200
	G3S12002D
	G5S12002D

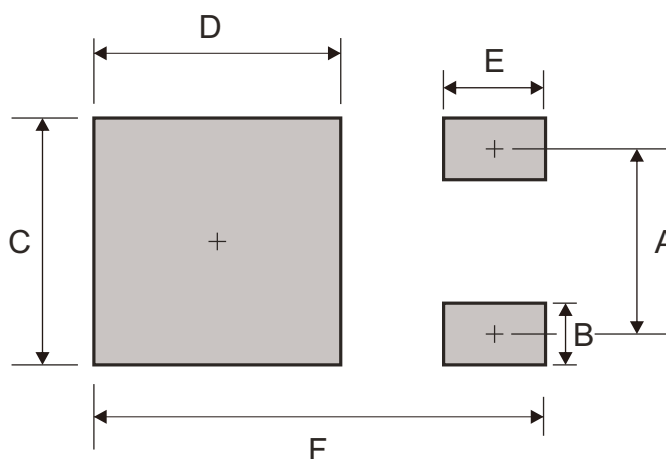


☐ = Comchip Logo

xxxxxx = Control code  
(x from 6 to 11)

## Suggested P.C.B. PAD Layout

SIZE	TO-263 / D2PAK	
	(mm)	(inch)
A	5.08	0.200
B	1.10	0.043
C	10.80	0.425
D	8.30	0.327
E	3.50	0.138
F	16.90	0.665



## Standard Packaging

Case Type	TUBE PACK	
	TUBE ( pcs )	BOX ( pcs )
TO-263/D2PAK	50	1,000